



75V NPN MEDIUM POWER HIGH GAIN TRANSISTOR IN SOT223

Description

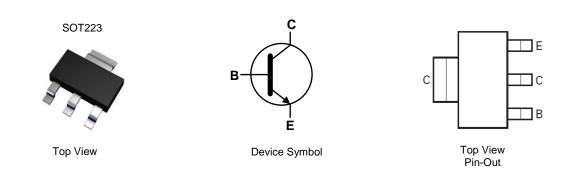
This bipolar junction transistor (BJT) is designed to meet the stringent requirements of Automotive Applications.

Features

- BV_{CEO} > 75V
- I_C= 4.5A High Continuous Collector Current
- I_{CM} = 10A Peak Pulse Current
- Low Saturation Voltage V_{CE(sat)} < 120mV @ 1A
- hFE > 300 @ Ic=1A for a High Gain Hold-Up
- R_{CE(sat)} = 78mΩ at 4.5A for a Low Equivalent On-Resistance
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Mechanical Data

- Case: SOT223
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish—Matte Tin Plated Leads. Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.112 grams (Approximate)



Ordering Information (Notes 4 & 5)

| Part Number | Compliance | Marking | Reel Size (inches) | Tape Width (mm) | Quantity per Reel |
|-------------|------------|----------|--------------------|-----------------|-------------------|
| FZT1053AQTA | Automotive | FZT1053A | 7 | 12 | 1,000 |

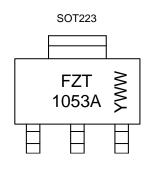
Notes: 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied. 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.

5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



FZT1053A = Product Type Marking Code YWW = Date Code Marking Y or \overline{Y} = Last Digit of Year (ex: 9 = 2019) WW or $\overline{W}W$ = Week Code (01 to 53)



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|------------------------------|------------------|-------|------|
| Collector-Base Voltage | V _{CBO} | 150 | V |
| Collector-Emitter Voltage | V _{CEO} | 75 | V |
| Emitter-Base Voltage | V _{EBO} | 7 | V |
| Continuous Collector Current | lc | 4.5 | А |
| Continuous Base Current | IB | 500 | mA |
| Peak Pulse Collector Current | I _{CM} | 10 | А |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | | Symbol | Value | Unit | |
|---|-----------|---------------------|-------------|------|--|
| | (Note 6) | | 3.0 | | |
| Power Dissipation | (Note 7) | | 2.0 | w | |
| | (Note 8) | PD | 1.6 | vv | |
| | (Note 9) | | 1.2 | | |
| | (Note 6) | | 41.7 | | |
| Thermal Resistance, Junction to Ambient | (Note 7) | D | 62.5 | | |
| | (Note 8) | R _{0JA} | 78.1 | °C/W | |
| | (Note 9) | | 104 | | |
| Thermal Resistance Junction to Lead | (Note 10) | $R_{	ext{	heta}JL}$ | 10.9 | | |
| Operating and Storage Temperature Range | | TJ, TSTG | -55 to +150 | °C | |

ESD Ratings (Note 11)

| Characteristic | Symbol | Value | Unit | JEDEC Class |
|--|---------|-------|------|-------------|
| Electrostatic Discharge—Human Body Model | ESD HBM | 4000 | V | 3A |
| Electrostatic Discharge—Machine Model | ESD MM | 400 | V | С |

Notes: 6. For a device mounted with the collector lead on 52mm x 52mm 2oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
Same as Note 6, except the device is mounted on 25mm x 25mm 2oz copper.

8. Same as Note 6, except the device is mounted on 25mm x 25mm 1oz copper.

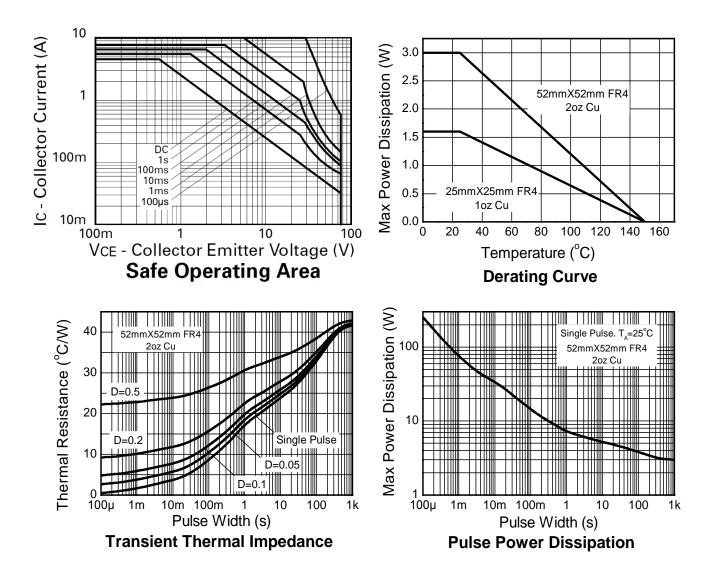
9. Same as Note 6, except the device is mounted on minimum recommended pad layout.

10. Thermal resistance from junction to solder-point (at the end of the collector lead).

11. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information





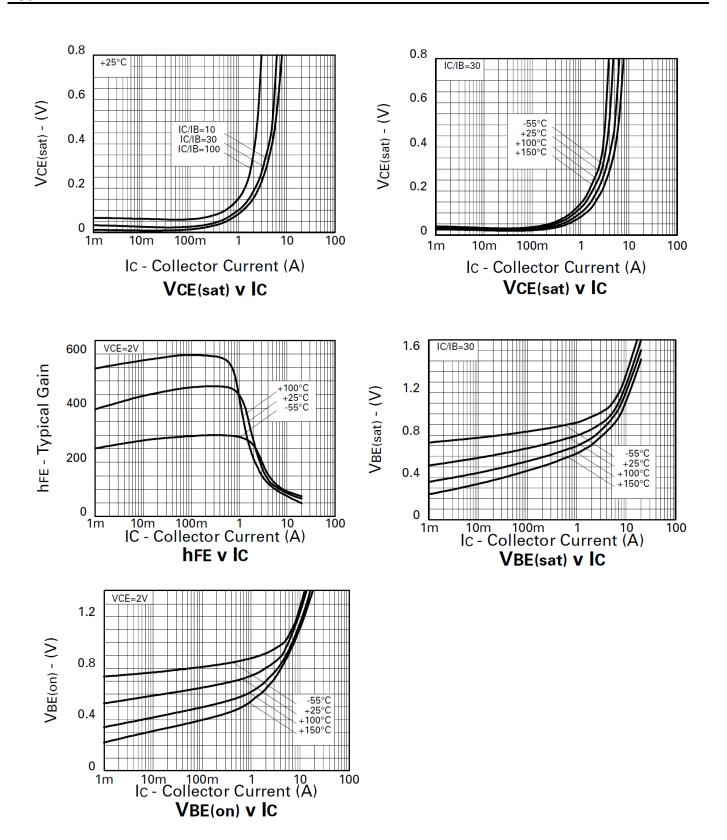
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|----------------------|-----|-----|-------|------|--|--|
| Collector-Base Breakdown Voltage | BV _{CBO} | 150 | 250 | _ | V | $I_{\rm C} = 100 \mu {\rm A}$ | |
| Collector-Emitter Breakdown Voltage | BV _{CES} | 150 | 250 | _ | V | I _C = 100μA | |
| Collector-Emitter Breakdown Voltage (Note 12) | BV _{CEO} | 75 | 100 | _ | V | $I_{C} = 10 \text{mA}$ | |
| Collector-Emitter Breakdown Voltage | BV _{CEV} | 150 | 250 | _ | V | $I_{C} = 100 \mu A, V_{EB} = 1 V$ | |
| Emitter-Base Breakdown Voltage | BV _{EBO} | 7.0 | 8.8 | — | V | I _E = 100μA | |
| Collector Cutoff Current | I _{CBO} | _ | 0.9 | 10 | nA | V _{CB} = 120V | |
| Collector Cutoff Current | ICES | _ | 1.5 | 10 | nA | V _{CES} = 120V | |
| Emitter Cutoff Current | I _{EBO} | _ | 0.3 | 10 | nA | $V_{EB} = 4V$ | |
| | | 270 | 440 | _ | _ | $I_{C} = 10 \text{mA}, V_{CE} = 2 \text{V}$ | |
| | | 300 | 450 | 1,200 | | $I_{C} = 0.5A, V_{CE} = 2V$ | |
| DC Current Transfer Static Ratio (Note 12) | h _{FE} | 300 | 450 | _ | | $I_{C} = 1A, V_{CE} = 2V$ | |
| | | 40 | 60 | _ | | $I_{C} = 4.5A, V_{CE} = 2V$ | |
| | | | 20 | _ | | $I_{C} = 10A, V_{CE} = 2V$ | |
| | V _{CE(sat)} | _ | 21 | 30 | mV | $I_{\rm C} = 0.2$ A, $I_{\rm B} = 20$ mA | |
| | | _ | 55 | 75 | | $I_{C} = 0.5A, I_{B} = 20mA$ | |
| Collector-Emitter Saturation Voltage (Note 12) | | _ | 150 | 200 | | $I_{C} = 1A, I_{B} = 10mA$ | |
| | | | 160 | 210 | | $I_{\rm C} = 2A, I_{\rm B} = 100 {\rm mA}$ | |
| | | _ | 350 | 440 | | I _C = 4.5A, I _B = 200mA | |
| Base-Emitter Saturation Voltage (Note 12) | V _{BE(sat)} | _ | 900 | 1,000 | mV | $I_{\rm C} = 3A, I_{\rm B} = 100 {\rm mA}$ | |
| Base-Emitter Turn-On Voltage (Note 12) | V _{BE(on)} | _ | 825 | 950 | mV | $I_C = 3A, V_{CE} = 2V$ | |
| Transitional Frequency (Note 12) | f _T | _ | 140 | _ | MHz | $I_{C} = 50 \text{mA}, V_{CE} = 10 \text{V}, $ f = 100MHz | |
| Output Capacitance | C _{obo} | _ | 21 | 30 | pF | V _{CB} = 10V, f = 1MHz | |
| Queitabing Time | t _{on} | | 162 | _ | ns | $V_{CC} = 50V, I_C = 2A,$ | |
| Switching Time | t _{off} | _ | 900 | _ | ns | $I_{B1} = I_{B2} = \pm 20 \text{mA}$ | |

Note: 12. Measured under pulsed conditions. Pulse width \leq 300µs. Duty cycle \leq 2%.



Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

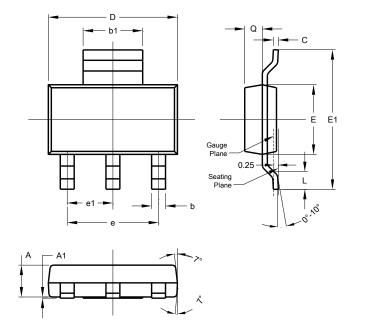




Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

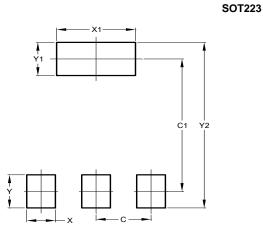
SOT223



| SOT223 | | | | | |
|--------|----------------------|------|------|--|--|
| Dim | Min | Max | Тур | | |
| Α | 1.55 | 1.65 | 1.60 | | |
| A1 | 0.010 | 0.15 | 0.05 | | |
| b | 0.60 | 0.80 | 0.70 | | |
| b1 | 2.90 | 3.10 | 3.00 | | |
| С | 0.20 | 0.30 | 0.25 | | |
| D | 6.45 | 6.55 | 6.50 | | |
| E | 3.45 | 3.55 | 3.50 | | |
| E1 | 6.90 | 7.10 | 7.00 | | |
| е | - | - | 4.60 | | |
| e1 | - | - | 2.30 | | |
| L | 0.85 | 1.05 | 0.95 | | |
| q | 0.84 | 0.94 | 0.89 | | |
| All I | All Dimensions in mm | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



| Dimensions | Value (in mm) |
|------------|---------------|
| С | 2.30 |
| C1 | 6.40 |
| Х | 1.20 |
| X1 | 3.30 |
| Y | 1.60 |
| Y1 | 1.60 |
| Y2 | 8.00 |



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